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Application Number	10/809,867	
Filing Date	March 26, 2004	
First Named Inventor	Masanori UEDA et al.	
Art Unit	3729	
Examiner Name	Anthony D. Tugbang	
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	U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No.1	Document Number	Number-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, When Relevant Passages or Relevant Flages Appear	
	1	US-					
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Examiner Initials*	Cite No.1	Foreign Patent Document	Country Code <sup>3</sup>	Number Kind Code (If known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Τ*
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Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.						T <sup>2</sup>
/ADT/		Hideki TAKAGI, "Room-Temperature Bonding of Silicon Wafers by means of the Surface Activation Method" Report of Mechanical Engineering Laboratory No. 189, December 2000, Pages 1-7, and 68-84.					AB	

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		Date	- 10 1 10 5
Examiner	/A. Dexter Tugbang/	L .	5/24/07
Signature	/A. Dekter rugzung/	Considered	

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. <sup>1</sup>Unique citation designation number. <sup>2</sup>See attached Kinds of U.S. Patent Documents. <sup>3</sup>Enter Office that issued the document, by the two-letter code. <sup>4</sup>For Japanese patent documents, the Indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to place a check mark here if English language translation is attached. AB indicates that only an English language abstract is attached.